

Shining Emitter in Stable Host: Design Halide Perovskite Scintillators for X-Ray Imaging from Commercial Concept

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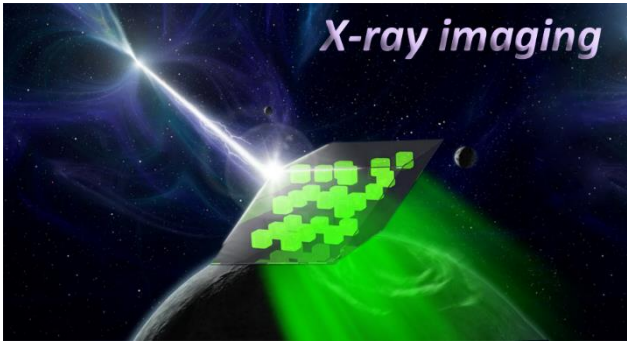
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Abstract: Halide perovskite (HP) nanocrystals (NCs) have recently shown great potential for X-ray detection and imaging. However, the practical application is still a long way to go with lots of technical requirements waiting to be fulfilled, including structure optimization, stability enhancement, and cost reduction. A design principle in this beginning stage is urgently needed but still lacking. Herein, with an “emitter-in-matrix” principle refined from commercial scintillators, CsPbBr₃@Cs₄PbBr₆ with emissive CsPbBr₃ NCs embedded inside solid-state Cs₄PbBr₆ host is brought to X-ray sensing and imaging. The Cs₄PbBr₆ matrix not only enhances the attenuation of X-rays but also dramatically improves the stability of CsPbBr₃ NCs. A favorable optical design with the Cs₄PbBr₆ matrix being transparent to the emission from CsPbBr₃ NCs enables efficient light output. As a result, stable and sensitive scintillation response to X-ray signals is demonstrated with superior linearity and ultrahigh time resolution. In order to show the huge potential for practical application, X-ray imaging using a large-area film (360 mm×240 mm) by blade-coating technique is carried out to obtain a high-quality image of human eye-invisible interior structures. In addition to the above advantages in optics, CsPbBr₃@Cs₄PbBr₆ also enjoys facile solution synthesis with large scalability, excellent repeatability and low cost.

Keywords: x-ray imaging, scintillator, halide perovskite, CsPbBr₃@Cs₄PbBr₆, zero-dimensional perovskite

TOC graphic



X-rays are high-energy electromagnetic radiation with a strong penetrability, therefore it can be used to detect inner situations that cannot be seen by human eyes. Since the discovery of X-ray in 1895 by Wilhelm Röntgen,¹ it has been widely applied in multiple supremely important fields, including diagnostic radiology,² non-destructive testing,³ safety monitoring,⁴ nuclear or radiation prevention and so on.⁵ The X-ray irradiation detection can be classified into two types: 1) a direct way by semiconductors;⁶ 2) an indirect way using scintillators.⁷ Although the direct detectors (a-Se, HgI₂, CdTe, CdZnTe, *et al.*) are renowned for high resolution,⁸ the response rate is usually low. Furthermore, the difficulties in fabricating large-sized wafer with small noise current but large $\mu\tau$ (mobility-lifetime) product still impose impediment in obtaining satisfactory price/performance ratio.⁹ In contrast, scintillators that downconvert high-energy rays into ultraviolet-visible (UV-vis.) light for indirect sensing of X-rays, are more industrially feasible with low cost, rich choices for customization, and flexible combination with commercially-mature sensing arrays (such as amorphous Si photodiodes, TFT arrays, photomultiplier tubes (PMTs), complementary metal-oxide semiconductor (CMOS), silicon avalanche photodiodes or charge-coupled devices (CCDs)) for X-ray imaging,¹⁰ therefore have attracted increasing research attention.

The strong penetration and radiation damage should be taken into consideration when designing scintillators, hence the stable forms of thick film (CsI:Tl for example) or bulk crystal are widely adopted in market. However, the film was fabricated by low-pressure thermal evaporation,^{11, 12} and bulk crystals are widely grown by Czochralski method with an ultrahigh processing temperature over 1700 °C, all these processes would result in high manufacture cost.¹³ Moreover, when considering the well-known quantum size effect, one of the most important basic principles to endow materials with bright radioluminescence,^{14, 15} evaporated films and bulk crystals do not usually own decent scintillation behavior. As a result, the combination of reliable stability and superior scintillation performance in scintillators is the key challenge in material design.

That's where the "emitter-in-matrix" design principle, refined from commercial scintillators, takes effect. Usually rare-earth dopants as emitting centers are incorporated into crystal host to tackle the contradiction abovementioned, thereby producing the most-widely used scintillators including CsI:Tl, NaI:Tl, Gd₂O₂S:Tb, LaBr₃:Ce, LaCl₃:Ce, CaI₂:Eu, CaF₂:Eu and so on.¹⁶⁻²¹ Alternatively, these years have witnessed the prosperous development of fluorescent nanomaterials with low-temperature solution synthesis, higher quantum yields (QYs), narrower linewidth, and tunable emissions to replace rare-earth emitters in the next-generation scintillation technique.²²⁻²⁶ However, after developing so many kinds of nanomaterials, they have yet to be applied in the market to date. The market is the most honest referee to inform the commercial feasibility, the failure of nanomaterials in scintillators can be ascribed to their rapid degradation upon irradiation,^{26, 27} as well as the easy formation of nonradiative recombination paths to compromise the optical properties.²⁸

Recently, a star material known as halide perovskite (HP), owning superior optoelectronic properties and containing heavy element Pb,²⁹⁻³³ was demonstrated to be efficient X-ray sensors. Firstly the direct strategy was explored,³⁴⁻⁴⁰ but soon the indirect method using HP materials as scintillators was presented to show facility, better response rate, and comparable resolution.^{41, 42} HP single crystals have presented respectable scintillation behavior but only at a very low temperature (<130 K), which is less practical and is unlikely to popularize.⁴³ In comparison, HP nanocrystals (NCs) are more promising with admirable scintillation performance at room temperature,^{42, 44} however, the problem is that they suffer from predictable poor stability to X-ray irradiation not only because of their intrinsic high sensitivity to multiple environmental species including light, heat, and moisture,⁴⁵⁻⁵¹ but also the well-revealed aggregation and phase transition issues.⁵²⁻⁵⁵ Thus, achieving both high scintillation performance and reliable stability upon X-ray irradiation in HPs is still effortful.

In this work, following the "emitter-in-matrix" designing concept refined from commercial scintillators, the CsPbBr₃@Cs₄PbBr₆ system with CsPbBr₃ NCs embedded inside Cs₄PbBr₆

crystal matrix is explored for X-ray sensing and imaging. The benefits of such design are comprehensively introduced: 1) The Cs_4PbBr_6 matrix is not only to enhance the attenuation of X-ray but also to greatly improve the stability of the embedded CsPbBr_3 NCs. 2) At the same time, the wide-bandgap Cs_4PbBr_6 is transparent to the green emission of CsPbBr_3 NCs for efficient light output; 3) The delicate $\text{CsPbBr}_3@ \text{Cs}_4\text{PbBr}_6$, however, enjoys facile solution synthesis with large scalability, excellent repeatability and low-cost fabrication, a high QY up to 60%. As a result, the $\text{CsPbBr}_3@ \text{Cs}_4\text{PbBr}_6$ shows scintillation response to X-rays with excellent linearity and ultrashort decay time, which ensures low-dose sensing and high-quality imaging. Finally, *via* a facile and non-vacuum blade coating technique, a large-area film with a size up to 360 mm \times 240 mm is fabricated as an X-ray screen, by which a clear image of invisible interior structure is presented with high quality to show its great potential for practical use.

Results/Discussion

Design of HP scintillators from the “emitter-in-matrix” principle

The “emitter-in-matrix” design principle of scintillators toward X-ray sensing can be summed up as the following three aspects (**Figure 1a**): 1) The emitter should contribute to high-efficiency radioluminescence; 2) The matrix is required for not only stopping the X-rays but also high material stability; 3) The host should be optically transparent to the emission from the embedded emitters for suppressing photon loss. Figure 1b displays the typical emitter-in-matrix structure of commercial scintillators, in which rare-earth elements are usually used as the emitter, CsI: Tl for example, which is the most widely used thin film scintillator. Despite the adequate performance in these scintillators, the high-temperature procedures are quite complicated and expensive.^{56, 57}

HP NCs have recently been reported to be potential cost-effective scintillators for high-performance X-ray sensing. Significantly, while pure HP NCs suffer from the notorious

instability issue,⁵⁸ a system known as CsPbBr₃@Cs₄PbBr₆, where CsPbBr₃ NCs are embedded into Cs₄PbBr₆ matrix exactly following the “emitter-in-matrix” design principle (Figure 1c), has greatly encouraged the community with enhanced stability and comparable optical properties with pure CsPbBr₃ NCs.⁵⁹ It should first be mentioned that the origin of the bright green emission in CsPbBr₃@Cs₄PbBr₆ is still under debate,⁶⁰ some groups ascribe the emission to Cs₄PbBr₆ itself by mid-gap defect centers or self-trapped excitons,⁶¹⁻⁶⁸ while other groups believed it is the embedded but undiscovered CsPbBr₃ NC that accounts for the emission.^{59, 69-71} One of the focuses of this debate is whether there is CsPbBr₃ inclusions in Cs₄PbBr₆, since typical structural characterizations of X-ray diffraction (XRD) and transmission electron microscopy (TEM) usually fail to identify impurities in Cs₄PbBr₆. Even though some groups reported the detection of CsPbBr₃ phases, no convincing evidence was provided to tell if they are segregated NCs inside Cs₄PbBr₆ or phase-pure by-product. Therefore, researchers have recently turned to innovative methods such as pressure-induced phase transition and cathodoluminescence imaging.^{72, 73}

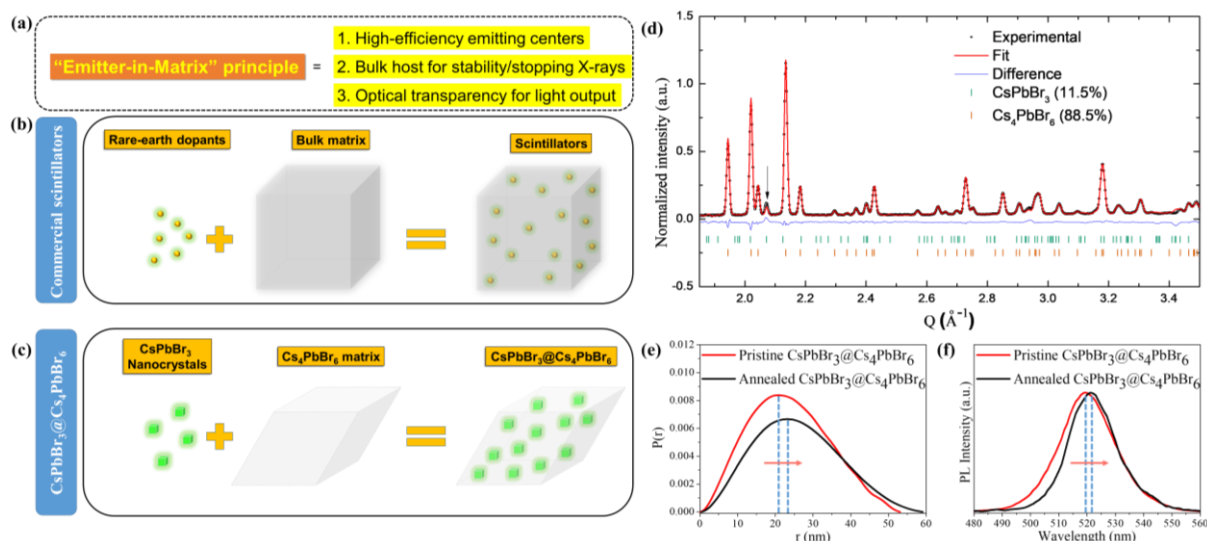


Figure 1. Design HP scintillators from the commercial “emitter-in-matrix” concept. (a) The three aspects of the “emitter-in-matrix” design principle. (b) Schematic illustration of the emitter-in-matrix structure of commercial scintillators (such as NaI: Tl). (c) Schematic view of the CsPbBr₃@Cs₄PbBr₆ structure, where CsPbBr₃ NCs are embedded into the Cs₄PbBr₆ matrix. (d) Neutron powder diffraction characterization to obtain the phase information and composition proportion of CsPbBr₃ and Cs₄PbBr₆ in the CsPbBr₃@Cs₄PbBr₆ system. (e) The size distribution of CsPbBr₃ NCs, PDDF, deduced from the SANS data. The red and black lines

correspond to pristine CsPbBr₃@Cs₄PbBr₆ and annealed CsPbBr₃@Cs₄PbBr₆, respectively. (f) PL spectra of pristine and annealed CsPbBr₃@Cs₄PbBr₆. The annealing temperature was 250 °C and the annealing time was 30 mins.

Herein, neutron scattering technique was carried out to confirm the presence of CsPbBr₃ NCs inside the Cs₄PbBr₆ host with detailed phase information and size information. Firstly, neutron powder diffraction was conducted to obtain the phase information, the pristine and fitted data are shown in Figure 1d, the combination of hexagonal Cs₄PbBr₆ and orthorhombic CsPbBr₃ matches perfectly with the experimental curve. Although the content of CsPbBr₃ is very small (the molar fraction is 11.5%), the characteristic peak marked by the black arrow unambiguously points out its presence. The detailed crystallographic data by the fitting are given in **Table S1**. Further, small-angle neutron scattering (SANS) characterization was carried out for the size information of the CsPbBr₃ phase. SANS is a technique that uses elastically scattered neutrons in a small-angle region to study mesoscale structures (1 nm~ 100 nm) inside materials, the data is shown in **Figure S1**. Pair distance distribution function (PDDF) *versus* size distribution is presented in Figure 1e, the result shows that there are inhomogeneous nanostructures with the size of circa 20 nm within the Cs₄PbBr₆ host. Convincingly, the 518 nm emission and the 20 nm size matches well with the size-fluorescence relationship of CsPbBr₃ NCs in previous reports.^{74, 75} To directly correlate the emitting centers with the nanostructures unveiled by SANS, the sample was annealed at 250 °C for comparison. As shown in Figure 1f, the high-temperature annealing causes an increase in the size of the nanostructures, and subsequently, a red-shift in the photoluminescence (PL) spectra. It should be noted that the size of ~20 nm in CsPbBr₃ NCs means a weak quantum confinement, which may not fully explain the redshift of the emission. The redshift may also be partially linked to enhanced electron-photon coupling probably caused by the uncoordinated lattice expansion between the two phases under heat stress. What should also be kept in mind is that the presence of CsPbBr₃ in Cs₄PbBr₆ does not deny the other proposals of the bright emission, on which more insightful researches are still required.

Enhanced X-ray attenuation and irradiation stability by the Cs₄PbBr₆ matrix

When assessed as scintillators, the capability of attenuating X-rays is one of the most important parameters to be considered. In general, the X-ray attenuation can be described by an exponential function, $I/I_0 = \exp(-kx)$, in which k is the attenuation coefficient, x is the depth of penetration (the details can be found in the **Methods/Experimental section**). The attenuation behavior is correlated to the density and the X-ray absorption of constituent atoms, and therefore can be estimated accordingly. The calculated X-ray attenuation coefficients (@ 50 keV) of CsPbBr₃, Cs₄PbBr₆, Si, CsI:Tl and NaI: Tl are listed in **Table 1** for comparison. The result shows that the Cs₄PbBr₆ host helps enhance the X-ray attenuation when compared with pure CsPbBr₃. It has been unveiled that there are exciton transfer and radiative transfer from Cs₄PbBr₆ host to the CsPbBr₃ NCs as in traditional scintillators with rare-earth activators,^{76, 77} a discussion along with the photoluminescence excitation spectra (PLE) spectrum (@520 nm emission) in **Figure S2** is provided in the Supporting Information. Besides, although slightly smaller than that of NaI: Tl and CsI:Tl, the coefficient is much larger than Si. The plots of X-ray attenuation are shown and compared in **Figure 2a**. For the X-ray with 22 keV peak intensity in our experiment, the thickness of Cs₄PbBr₆ required to attenuate 99.5% X-ray intensity is estimated to be 424 μm , which can be reached by mature film preparation techniques such as blade coating.

Another contribution of Cs₄PbBr₆ matrix is to enhance the irradiation endurance of emitting CsPbBr₃ NCs. Pure CsPbBr₃ NCs suffer from the issues of phase transition and even aggregation upon light irradiation.⁵²⁻⁵⁵ Figure 2b displays the schematic illustration of this dynamic process. The advantage of the CsPbBr₃@Cs₄PbBr₆ structure is that the Cs₄PbBr₆ matrix can help to stabilize the CsPbBr₃ emitting centers with passivating the highly-active surface of CsPbBr₃ NCs and inhibiting the isolated CsPbBr₃ NCs from aggregation, as is illustrated in Figure 2c. Moreover, the emitter-in-matrix structure protects the interior CsPbBr₃

NCs from environmental species such as moisture and oxygen, which have been verified to accelerate degradation under irradiation.⁷⁸ We then compared the irradiation stability of pure CsPbBr₃ NCs (**Figure S3**, from hot injection method⁷⁹) and the CsPbBr₃@Cs₄PbBr₆. Since long-term X-ray irradiation is not executable in lab for safety sake, ultraviolet (UV) irradiation test was carried out instead. The irradiation stress was set as 30 W and the testing time was 4 h, during which the structure and PL were traced to evaluate the functionality retention. The XRD patterns are shown in Figure 2d, the characteristic peaks of CsPbBr₃ NCs become narrower after the test, which points out a crystal size increase according to the Scherrer equation. In contrast, the pattern of CsPbBr₃@Cs₄PbBr₆ shows no change, reflecting its irradiation robustness in air. Figure 2e is the evolution of integrated PL intensity *versus* irradiation time. For the CsPbBr₃ NCs, the emitting performance shows continuous decay under irradiation, and only 53% of the emission intensity remained after the test. Meanwhile, the red-shift in emission peak caused by aggregation-induced size increment was also observed (**Figure S4**). In the CsPbBr₃@Cs₄PbBr₆ sample, however, almost no change in PL spectra (**Figure S5**) and intensity were observed. This result confirms the significantly enhanced irradiation stability in CsPbBr₃@Cs₄PbBr₆ compared with pure CsPbBr₃ NCs, which sets the precondition for the practical X-ray sensing and imaging application.

Table 1. Calculated attenuation coefficients of some scintillators (@50 keV X-ray). The corresponding unit of thickness is mm.

Scintillator	Attenuation coefficient
CsPbBr ₃	3.58
Cs ₄ PbBr ₆	3.74
NaI:Tl	3.84
CsI:Tl	5.81
Si	0.12

Note: Cs₄PbBr₆ denotes pure Cs₄PbBr₆ host rather than CsPbBr₃@Cs₄PbBr₆ host.

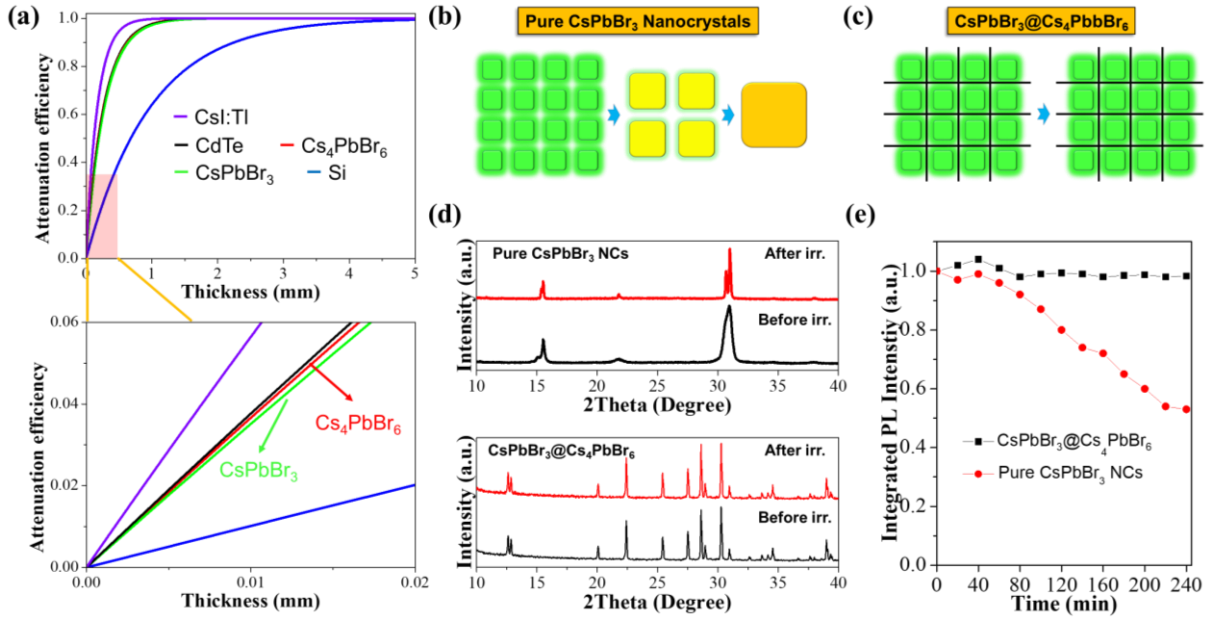


Figure 2. Enhanced X-ray attenuation and irradiation stability in CsPbBr₃@Cs₄PbBr₆ compared with pure CsPbBr₃ NCs. (a) X-ray attenuating plot of CsPbBr₃, CsPbBr₃@Cs₄PbBr₆, CsI:Tl, NaI:Tl and Si, respectively. The X-ray energy is 50 keV. (b) The aggregation effect causes fluorescence loss of the pure CsPbBr₃ NCs upon ultraviolet illumination. The green square is the initial HP NCs, the yellow square is intermediate state of the aggregated NCs, and the orange square represents the final state of the aggregated NCs. (c) The proposed robustness of CsPbBr₃@Cs₄PbBr₆ structure upon ultraviolet illumination. (d) The change of XRD patterns for pure CsPbBr₃ NCs and CsPbBr₃@Cs₄PbBr₆ after the irradiation test (30 W@365 nm for 4 h). (e) Evolution of the integrated PL intensity of CsPbBr₃@Cs₄PbBr₆ and pure CsPbBr₃ NCs during the test.

Photon loss analysis from bandgap simulations

The incident X-rays excite CsPbBr₃ NCs to emit bright radioluminescence. To realize efficient photon output in typical “emitter-in-matrix” scintillators, the self-absorption by the matrix should be very low, *i.e.*, the matrix should be optically transparent to the emission from the inside emitting centers. The proposed situation in CsPbBr₃@Cs₄PbBr₆ is shown in **Figure 3a**. The optical bandgap of Cs₄PbBr₆ was then estimated from density functional theory (DFT) calculation, the details of the calculation can be found in experimental section (*Simulation Details*). The result (Figure 3b) shows its bandgap reaches up to 3.8 eV, validating that the wide-bandgap Cs₄PbBr₆ matrix ensures the output of low-energy emission (~2.4 eV) from embedded CsPbBr₃ NCs. Thus, it can be concluded that the Cs₄PbBr₆ matrix has negligible absorption on the internal CsPbBr₃ emitting photons. The corresponding absorption and

radioluminescence (by X-rays with peak intensity of 22 keV) spectra of $\text{CsPbBr}_3@ \text{Cs}_4\text{PbBr}_6$ are shown in Figure 3c. The absorption feature in the UV region matches well with the above simulated bandgap of Cs_4PbBr_6 . Meanwhile, a single emission peak at 528 nm can be found in the radioluminescence spectrum. Interestingly, there is a redshift of 10 nm compared with that of $\text{CsPbBr}_3@ \text{Cs}_4\text{PbBr}_6$ (peaked at 518 nm, Figure 1f). This redshift reduces the overlap of the radioluminescence and absorption spectra, hence lowering the self-absorption of CsPbBr_3 inclusions themselves to further ensure efficient light output.

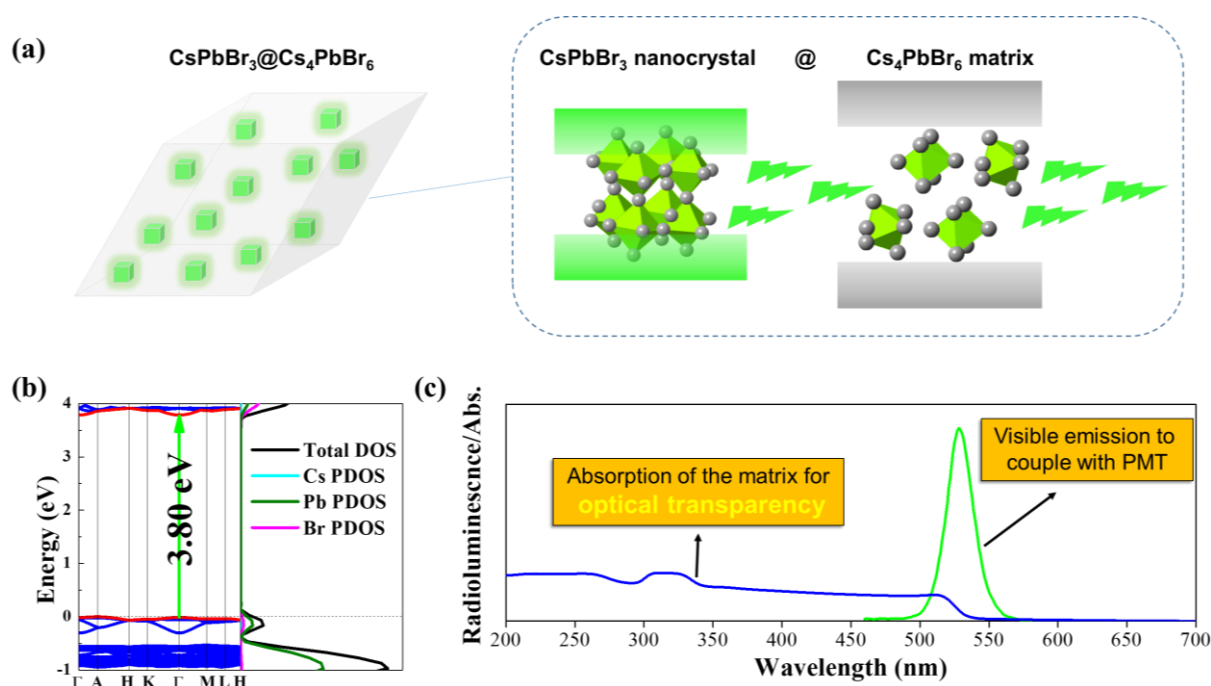


Figure 3. Transparent Cs_4PbBr_6 matrix enabling efficient light output. (a) Schematic view of the bandgap of the CsPbBr_3 core and the Cs_4PbBr_6 matrix. (b) DFT simulation of the bandgap of the Cs_4PbBr_6 matrix. (c) Radioluminescence (X-ray@22 keV) and absorption spectrum analysis of the $\text{CsPbBr}_3@ \text{Cs}_4\text{PbBr}_6$.

X-ray sensing and imaging

The efficient light output enables the sensing of weak X-ray signal, which is especially important in biomedical applications. Evidence of radiation-induced cancer risk at a dose above 100 mSv (equals to 100 mGy_{air}) shows that an estimation of ~2% of the cancers could be related to CT radiation in the United States (2007).⁸⁰ Keep this in mind, the radioluminescence response of the $\text{CsPbBr}_3@ \text{Cs}_4\text{PbBr}_6$ with a low X-ray dose was firstly tested. When combined with

polymer (polystyrene here, termed as PS in the following), the film of $\text{CsPbBr}_3@ \text{Cs}_4\text{PbBr}_6$ can be deposited with high thickness even up to centimeter-scale to fully absorb X-rays. The radioluminescence response is enhanced upon increasing X-ray irradiation as shown in **Figure S6**, and related discussion is offered in **Figure S7**. Significantly, excellent linearity can be found ranging from $93.75 \mu\text{Gy}_{\text{air}}/\text{s}$ to $1340.37 \mu\text{Gy}_{\text{air}}/\text{s}$ (**Figure 4a**), which means in this range the scintillation response and the radiation intensity can be predictably correlated. Significantly, this range is chosen referring to practical application, for example, the total irradiation dose for one-time chest computed tomography (CT) is 0.5 mSv-1 mSv, therefore, this linear response range fully meets the requirement of practical use with the exposure time of less than 1s.

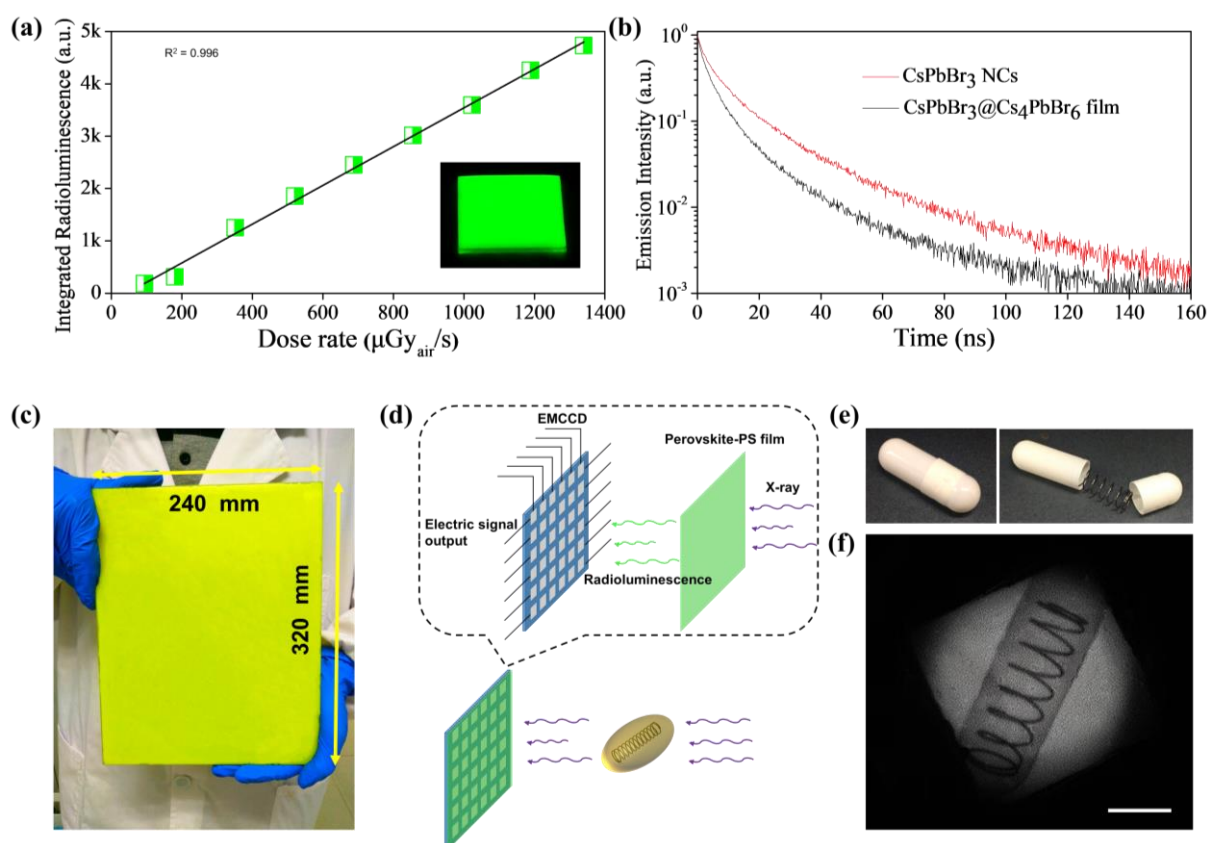


Figure 4. Scintillation behaviour and X-ray imaging of $\text{CsPbBr}_3@ \text{Cs}_4\text{PbBr}_6$. (a) The linear relationship between the integrated PL intensity of the $\text{CsPbBr}_3@ \text{Cs}_4\text{PbBr}_6$ film and the X-ray dose. Inset: the fluorescent film of $\text{CsPbBr}_3@ \text{Cs}_4\text{PbBr}_6$ under X-ray excitation. (b) Emission decay spectra of the $\text{CsPbBr}_3@ \text{Cs}_4\text{PbBr}_6$ film and the pure CsPbBr_3 NCs, respectively. (c) Large-area film of the $\text{CsPbBr}_3@ \text{Cs}_4\text{PbBr}_6$ by low-cost blade-coating technique. (d) A self-built system for X-ray imaging. The target material is placed between the X-ray source and the sensing component. The sensing component is constructed by covering the $\text{CsPbBr}_3@ \text{Cs}_4\text{PbBr}_6$ film onto an EMCCD. (e) Photographs of the target material—a capsule containing a spring inside. (f) The obtained image by the X-ray imaging, which clearly shows the human eye-invisible metal spring inside. The scale bar is 1.5 mm.

Another important figure-of-merit of the scintillator is the decay time. As demonstrated above, the radioluminescence of commercial “emitter-in-matrix” based scintillators belongs to the emission of rare-earth elements, which suffer from slow decay rate that impedes their application in instant photography. In the CsPbBr₃@Cs₄PbBr₆ here, benefiting from additional confinement of Cs₄PbBr₆, the recombination dynamics for radiative emission is further accelerated.⁷¹ Figure 4b is the emission decay characterization with ultraviolet excitation, while the lifetime in typical CsPbBr₃ NCs by the widely adopted hot injection method is ~5 ns, a faster decay rate with ~3 ns lifetime is observed in CsPbBr₃@Cs₄PbBr₆, the excitation fluence for the two samples are the same. The first-order decay is caused by geminate electron-hole recombination accelerated by the confinement effect in type I band alignment, the slow decays are probably caused by biexciton and Auger quenching.⁷¹ In **Table 2**, a series of the decay time of commercial scintillators for comparison is also listed, the CsPbBr₃@Cs₄PbBr₆ is found to own the fastest decay, which guarantees the high time-resolution for X-ray pulses.

Table 2. Decay time data of the CsPbBr₃@Cs₄PbBr₆ scintillator as compared with some commercialized scintillators.^{81, 82}

Scintillator	Decay time (ns)
NaI:Tl	230
CsI:Tl	1000
CsI:Na	630
CsI	16
BGO	300
ZnWO ₄	5000
CdWO ₄	5000
BaF ₂ :Ce	60
LaF ₂ :Ce	27
CeF ₂	40
YAlO ₃ :Ce	30
Lu ₂ SiO ₅ :Ce	40
Y ₃ Al ₅ O ₁₂ :Ce	65
Bi ₄ Ge ₃ O ₁₂	300
(Y,Gd) ₂ O ₃ :Eu	1000000
Gd ₂ O ₂ S:Pr,Ce,F	3000
CsPbBr₃@Cs₄PbBr₆	3

Ultimately, to further verify its potential for practical X-ray imaging, a large-area film with the size up to 320 mm × 240 mm was fabricated with ease by facile blade coating as shown in Figure 4c. A system illustrated in Figure 4d was built to show the X-ray imaging capability of the CsPbBr₃@Cs₄PbBr₆. The target material was placed between the X-ray source and the detecting component. Herein, a capsule containing a metal spring inside is used (Figure 4e), the inside spring cannot be seen by human eyes. When exposed to X-ray irradiation, the inside metal spring affords stronger X-ray attenuation than the capsule, therefore causing spatial intensity contrast. The signal contrast can be translated by the CsPbBr₃@Cs₄PbBr₆ film into difference of radioluminescence intensity, which is then read out as an image *via* an electron multiplying charge-coupled device (EMCCD). The obtained image (Figure 4f) clearly shows the inside metal spring. And to evaluate the effect, imaging with commercial CsI:Tl was also carried out for comparison as shown in **Figure S8**. This result confirms the CsPbBr₃@Cs₄PbBr₆

here can be readily integrated into commercially-mature devices for X-ray sensing and imaging. The persistence of the CsPbBr₃@Cs₄PbBr₆ scintillator was tested further. The same imaging test was carried out every two months, during the test no encapsulation was conducted. As shown in **Figure S9**, the quality of the image remained high after 4 months, which points out the long-term reliability of CsPbBr₃@Cs₄PbBr₆ scintillator for X-ray imaging.

Solution synthesis and preliminary cost analysis

After confirming the superior scintillation performance, cost is also taken into consideration for industrialization. The delicate CsPbBr₃@Cs₄PbBr₆, however, enjoys facile, up-scalable, highly repeatable and low-cost solution synthesis. The illustration of the procedure can be found in **Figure 5a**. In brief, stoichiometric CsBr and PbBr₂ were dissolved in dimethyl sulfoxide (DMSO) to form the precursor, then the precursor was directly mixed with preheated toluene (120°C) that serves as antisolvent to force recrystallization of CsPbBr₃@Cs₄PbBr₆.⁸³ All procedures were completed in open air. Figure 5b is the large-scale synthesis with the yield of products reaching >15 grams from one-pot synthesis. The scanning electron microscopy (SEM) image is presented in **Figure S10**, A well-defined parallelepiped shape consistent with the crystallographic structure can be observed,^{64, 84} which indicates a favorable crystallization process and high crystallinity. As a result, the QY of CsPbBr₃@Cs₄PbBr₆ products reaches up to 60%. Notably, the size of the CsPbBr₃@Cs₄PbBr₆ particles is in the micron scale, which helps to prevent light scattering for efficient output.⁸⁵ In addition to the convenient operation and rapid scalability, solution synthesis is also highly repeatable. The fabrication process 10 times to compare the corresponding PL spectra of the products. The result is presented in **Figure S11**, a perfect overlap can be observed, which indicates the superior reliability in the fabrication process for commercial synthesis.

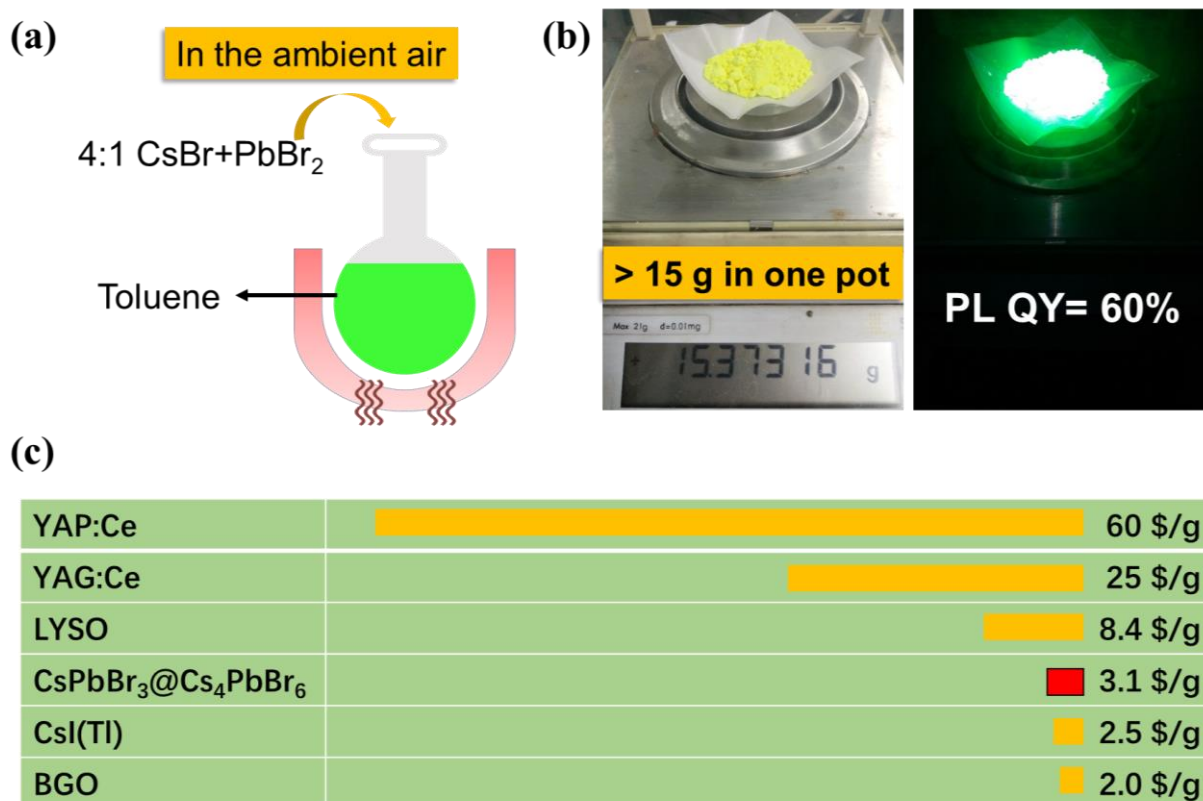


Figure 5. Design of commercial synthesis to obtain high-quality CsPbBr₃@Cs₄PbBr₆. (a) Facile solution preparation of the CsPbBr₃@Cs₄PbBr₆. (b) Up-scale synthesis of the CsPbBr₃@Cs₄PbBr₆ with high QYs. (c) Cost/price comparison of the CsPbBr₃@Cs₄PbBr₆ and some commercial scintillators.

Figure 5c gives the preliminary cost analysis of CsPbBr₃@Cs₄PbBr₆ products to compare with the prices of some widely-used commercial scintillators. It should be noted that the price of these commercialized scintillators highly depends on customized processings, here the price is only for the crude ingots the same as CsPbBr₃@Cs₄PbBr₆ to ensure a fair comparison. The result shows that the cost of CsPbBr₃@Cs₄PbBr₆ is quite close to that of BGO (Bi₄Ge₃O₁₂) and CsI:Tl, but is much cheaper than YAP: Ce (YAP is YAlO₃), YAG:Ce (YAG is Y₃Al₅O₁₂), and LYSO ((Lu,Y)₂SiO₅:Ce). If the scalability and processing are taken into considerations, the cost will be lowered further, which convinces us of the commercial competitiveness of the CsPbBr₃@Cs₄PbBr₆ scintillator.

Conclusions

In conclusion, we have fabricated CsPbBr₃@Cs₄PbBr₆ as scintillators for practical X-ray sensing and imaging. To clarify its commercial perspective, we evaluate the matrix from the commercial concepts, including material structure, stability, optical properties, and manufacture cost. The results indicate CsPbBr₃@Cs₄PbBr₆ hold a series of advantages over the traditional rare-element based scintillators. Finally, a large-area CsPbBr₃@Cs₄PbBr₆ film (360 mm × 240 mm) fabricated by blade-coating technique imaging screen shows high-quality X-ray imaging. Sensitive scintillation response to X-ray signals is demonstrated with superior linearity and nanosecond scale decay. We have a reason to believe that the CsPbBr₃@Cs₄PbBr₆ scintillator is on its way to be the next generation X-ray imaging and detecting technology. Future work will focus on growing large-sized CsPbBr₃@CsPbBr₄ crystals for the advancement of this class of scintillator.

Methods/Experimental

Small-angle neutron scattering:

In this work, SANS was performed on the Small Angle Neutron Scattering (SANS) instrument at China Spallation Neutron Source (CSNS). The incident neutrons with wavelength of 1-9Å were defined by a double-disc bandwidth chopper, which is collimated to the sample by a pair of apertures. The experiment used the sample to detector distance of 4 m and a sample aperture of 6 mm. The 1m square detector array composed of 120 linear He-3 gas tubes with the diameter of 8 mm, which covers the Q-range between 0.01Å⁻¹ and 1Å⁻¹. The presented data correspond to ~120 min of data collection time for each sample (@50kW). Neutron data were corrected for background scattering (empty sample holder), transmission and detector efficiency, and set to absolute units.

Chemicals for preparing CsPbBr₃@Cs₄PbBr₆: CsBr (~99.5%, Aladdin), PbBr₂ (~99%, MACKLIN), dimethyl sulfoxide (DMSO, 99.8%, Aladdin), toluene (≥99.5%, Shanghai Lingfeng Chemical Reagents Co., LTD), polystyrene (PS, Aldrich, average Mw ~280, 000 by GPC).

Large-scale preparation of CsPbBr₃@Cs₄PbBr₆ by solution method: All chemicals were purchased from Aladdin and used without further purification. For typical large-scale synthesis, 20 mol CsBr and 5 mol PbBr₂ were dissolved in 100 ml dimethyl sulfoxide (DMSO) to form precursor. The precursor was heated at 100 °C, then 500 ml toluene was added into the heated precursor as antisolvent to force the precipitation. The solution was then vigorously stirred for at least 2 h to ensure a complete reaction of the reagents. To extract the products, the solution was placed still until the particles quickly sink to the bottom, then the supernatant was discarded, and the precipitates were washed with toluene before centrifugation was carried out to extract the precipitates. The centrifugation-washing procedure was repeated several times before the products were sent for vacuum drying.

Fabrication of the CsPbBr₃@Cs₄PbBr₆/PS film: Firstly, polystyrene (PS) was dissolved in toluene to form a ropy solution. The abovementioned CsPbBr₃@Cs₄PbBr₆ powder was grinded to uniformize and reduce the size of CsPbBr₃@Cs₄PbBr₆ particles. Then the ground CsPbBr₃@Cs₄PbBr₆ was added into the PS/toluene solution and vigorously stirred, the concentration is 0.2 g/ml. After complete stirring for at least 10 h, the solution was casted by blade coating, and dried naturally in the air to obtain a solid film.

Preparation of the CsPbBr₃ nanocrystals: The synthesis of CsPbBr₃ nanocrystals basically follow the method reported in previous work,⁷⁹ where the details can be found.

Characterizations: A commercially available Amptek Mini-X tube with a Ag target and 4 W maximum power output was used as the X-ray source. The total X-ray dose was modulated by changing the current of the X-ray tube and the distance between the device and the X-ray source. The radiation dose rate was calibrated using a Radcal ion chamber dosimeter. A SPEX 8000 Mixer Mill was employed in this experiment; The XRD experiment were performed using Bruker D8 Advance XRD system; SEM images were captured by a Quant 250FEG instrument; The reflectance and photoluminescence spectra were measured by a SHIMADZU UV-3600 UV-VIS-NIR spectrophotometer and a Cary Eclipse Fluorescence Spectrophotometer, respectively; The lifetimes of PL were detected by a homemade instrument with a 375 nm picosecond lasers; The photoluminescence (PL) quantum yield (QY) was obtained by a HORIBA Fluomax-4 spectrometer; All the device characterizations were conducted at room temperature in ambient air. For testing the photostability, CsPbBr₃@Cs₄PbBr₆ powders and pure CsPbBr₃ nanocrystals were exposed under a UV lamp with a power of 30 W for 4 h, the wavelength of the light is 365 nm.

Neutron powder diffraction:

Neutron diffraction measurement was performed at the time of flight (TOF) general purpose powder diffractometer (GPPD) at China Spallation Neutron Source (CSNS). Decoupled poisoned hydrogen moderator (DPHM) is chosen in this measurement. The powder sample position is located in a vacuum chamber with a diameter of 1.2 m. Neutron diffraction pattern was collected at room temperature with wavelength from 0.1~4.9Å. In consideration of $Q=4\pi\sin\theta/\lambda$. Three detector banks (high-angle, 90°, low-angle) provide Q-range 0.22 Å⁻¹ ~ 125.66 Å⁻¹.

Simulation details: All the DFT calculations were performed using the Vienna *ab initio* simulation package (VASP), under periodic boundary conditions.⁸⁶ The projector-augmented-

wave (PAW) potential with cesium (Cs), lead (Pb), and bromine (Br) is described as valence electrons.⁸⁷ Geometry optimization and electronic band structure were carried out using the Perdew-Burke-Ernzerhof (PBE) exchange-correlation functional.⁸⁸ A kinetic energy cutoff of 500 eV was set on a grid of 6×6×4 k-points for tetragonal CsPbBr₃, and on a grid of 5×5×4 k-points for hexagonal Cs₄PbBr₆.

Calculation of the X-ray attenuation coefficients:

A narrow beam of monoenergetic photons with an incident intensity I_0 , penetrating a layer of material with mass thickness x and density ρ , emerges with intensity I given by the exponential attenuation law:

$$I/I_0 = \exp[-(\mu/\rho)*x] \quad (\text{eq 1})$$

Where I_0 is the initial intensity of the X-ray, I is the intensity of X-ray at the mass thickness of x , ρ is the density of the dense matter, x is defined as mass thickness per unit area and is obtained by multiplying the thickness t by the density ρ , *i.e.*, $x=\rho t$. Therefore, eq 1 can be expressed as:

$$I/I_0 = \exp[-(\mu/\rho)* \rho t] \quad (\text{eq 2})$$

For compounds like Cs₄PbBr₆ and CsPbBr₃, the value of mass attenuation coefficient, μ/ρ , can be obtained according to simple additivity:

$$\mu/\rho = \sum_i w_i (\mu/\rho)_i \quad (\text{eq 3})$$

where w_i is the fraction by weight of the i^{th} atomic constituent, and the $(\mu/\rho)_i$ values of each atom can be obtained from the following URL:

<https://physics.nist.gov/PhysRefData/XrayMassCoef/tab3.html>

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Supporting information

The Supporting Information is available free of charge via the Internet at <http://pubs.acs.org>. Phase information of CsPbBr₃ and Cs₄PbBr₆ in the CsPbBr₃@Cs₄PbBr₆ system obtained by the neutron scattering characterizations; Small-angle neutron scattering data of CsPbBr₃@Cs₄PbBr₆; The comparison of PLE spectrum and absorption spectrum; TEM image of the as-prepared CsPbBr₃ nanocrystals; Irradiation-induced degradation of pure CsPbBr₃ nanocrystals; PL spectra of as-prepared CsPbBr₃@Cs₄PbBr₆ and that after the irradiation test (30 W@365 nm for 4 h); Radioluminescence spectrum of the CsPbBr₃@Cs₄PbBr₆ under increasing X-ray doses; Light yield evaluation by comparing with commercial CsI:Tl scintillator; X-ray imaging using CsI:Tl scintillator; X-ray imaging results using the CsPbBr₃@Cs₄PbBr₆ scintillator obtained every two months; SEM image of the CsPbBr₃@Cs₄PbBr₆, the scale bar is 10 μm; PL spectra of 10 batches of CsPbBr₃@Cs₄PbBr₆ to show the excellent repeatability of the solution synthesis.

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